Diode Semiconductor Device - Page 1 of 1



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	nclosure Material:
C	Glass
C	Overall Length:
	0.250 inches
T	Ferminal Length:
1	1.300 inches
C	Overall Diameter:
С	0.225 inches
Ν	Mounting Method:
Т	Terminal
F	Features Provided:
ŀ	Hermetically sealed case
S	Semiconductor Material:
S	Silicon
٧	Voltage Rating In Volts Per Characteristic:
1	100.0 reverse voltage, peak
C	Current Rating Per Characteristic:
2	2.00 amperes average forward current averaged over a full 60-hz cycle
N	Maximum Operating Tempurature Per Measurement Point:
1	150.0 degrees celsius ambient air
T	Ferminal Type And Quantity:
2	2 uninsulated wire lead
S	Shelf Life:
٢	N/a
ι	Jnit Of Measure:
-	-
C	Demilitarization:
Ν	No
F	Filg:
	A110a0